



DOCUMENT CHANGE REQUEST

DCR number 1539 Changes required for: General

Originator: Steve Jeffery

Date: 2023/03/21

Date sent: 2022/11/30

Organisation: ESCC Executive

Status: IMPLEMENTED

Title: Transistors, Power, MOSFET, N-Channel, RAD-HARD, based on Type STRH100N10FSY3

Number: 5205/021

Issue: 9

Other documents affected:

Page:

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Paragraph:

2.7 (Parameter Drift Values)

Original wording:

The Maximum absolute limit for the 'Static Drain-to-Source On Resistance' Characteristic is 5 milliohms.

Proposed wording:

The currently-specified limit of 5 milliohms for 'Static Drain-to-Source On Resistance' shall be corrected to 35 milliohms.

Justification:

Correction of a typographical error which was introduced when DCR849 was implemented.

Attachments:

N/A

Modifications:

N/A

Approval signature:

Date signed:

2023-03-21